Phonon dispersion and lifetim es in $\mathrm{M} \mathrm{gB}_{2}$

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#### Abstract

W e m easure phonon dispersion and linew idth in a single crystal of $M \mathrm{gB}_{2}$ along the $-\mathrm{A}, \mathrm{M}$ and A-L directions using inelastic X R ay scattering. W e use D ensity Functional $T$ heory to com pute the e ect ofboth electron-phonon coupling and anharm on icity on the linew idth, obtain ing excellent agreem ent $w$ ith experim ent. A nom alous broadening of the $E_{2 g}$ phonon $m$ ode is found allalong $-A$. $T$ he dom inant contribution to the linew idth is alw ays the electron-phonon coupling.


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The discovery of 39 K superconductivity in M gB 2 (1] has led to in-depth study ofthem aterialand a picture has em erged ofa phonon $-m$ ediated superconductorw ith $m$ ultiple gaps [2, 3, [4], m oderate electron-phonon coupling (EPC) [3, [5, 6, 7], and anham on icity [3, [4, 8, [] ]. H ow ever no $m$ easurem ents exist conœeming either phonon dispersion or the evolution of phonon lifetim es over the $B$ rillouin Zone (B Z), due to the absence of large single crystals. $N$ eutron scattering on pow der sam ples [8, 10] has been lim ited to the determ ination of phonon density of states. Ram an spectroscopy, which is restricted to the B Z center, has shown that the optical m ode w th $\mathrm{E}_{2 \mathrm{~g}}$ sym $m$ etry, corresponding to in-plane distortions of the $B$ hexagons, is strongly dam ped [11, 12, 13, 14].

Phonon dam ping can be caused by (i) EPC mediated phonon decay into electron-hole pairs [15], or (ii) phonon-phonon interaction due to anharm onicity 16]. The linew idth (the inverse of the lifetim e) of a given phonon is the sum of both contributions. D irect deter$m$ ination of the contribution of each phonon $m$ ode to EPC [15] from the m easured linew idth is only possible if the anharm onic contribution is negligible [17] and is seem ingly questionable for $\mathrm{M} \mathrm{gB}_{2}$ where $m$ any calculations [3, [4, 8] suggest strong anharm onic e ects.

In this work we present the rst m easured phonon dispersion curves and linew idths (where possible) along three directions in the BZ, $-\mathrm{A}, \mathrm{M}$ and $\mathrm{A}-\mathrm{L} . \mathrm{W}$ e circum vented the problem of sam ple size by using high resohution inelastic scattering of a focused and intense $X-R$ ay beam at the European Synchrotron Radiation Facility (beam line $\mathbb{D} 28$ ), a technique 18] successfiully used in single crystalline sam ples and in particular for the $m$ easure$m$ ent of high energy optical $m$ odes [19]. To understand the $m$ echanism $s$ goveming the $m$ easured phenom ena, we calculated phonon dispersion, the contributions of EPC and anharm onicity to the linew idth and the structure factors using Density Functional Theory (D FT).

Sm all single crystals of $\mathrm{gB}_{2}$, suitable for inelastic X -
ray scattering experim ents have recently becom e available. The crystal used in our experim ent was grow n at a pressure of $30-35 \mathrm{kbar}$. A m ixture of $\mathrm{M} g$ and $B$ was put into a BN container in a cubic anvil device. T he tem perature w as increased during one hour up to 17001800 C , kept stable for 1-3 hours and decreased during 1-2 hours. A s a result plate-like $\mathrm{MB}_{2}$ crystals w ere form ed ofw hich we used a sam ple of about $400 \times 470 \times 40 \mathrm{~m}^{3}$; w ith a $m$ easured in-plane $m$ osaicity of $0: 007$. The beam incident on the sample was obtained from a high-resolution Silicon backscattering $m$ onochrom ator using the ( 888 8) re ection at an incident energy of 15.816 keV . T he X tray beam was focused onto the sam ple by a toroidalm irror into a spot of $270 \times 90 \mathrm{~m}^{2}$ (horizontal vertical), full width at half $m$ axim um (FW HM). Slits before the sam ple further lim ited the verticalbeam size to 30 m . T he scattered photons w ere analyzed in energy by ve spherical silicon crystalanalyzers operating at the sam ere ection order and m ounted in pseudo R ow land circle geom etry. The total energy resolution was 6.1 meV FW HM, as determ ined by a $t$ to a Lorentzian lineshape. The m om entum transfer $Q$ was selected by rotating the 7 m long analyzer arm around the sam ple position, in the horizontal plane, which also contained the linear x-ray polarization vector of the incident beam. T he $m$ om entum resolution was set to 0:04A ${ }^{1}$ in the horizontaldirection and $0: 07 \mathrm{~A}^{1}$ in the verticaldirection. T he follow ing $m$ easurem ents were perform ed at a tem perature of 300 K : i) $Q=\left(\begin{array}{ll}1 & 2\end{array}\right)$, in alm ost transverse con guration along the $-A$ direction, i.e. $w$ ith $Q \quad q \quad 0, q=(00)$ being the phonon wavevector, ii) $Q=(1-1+0)$, while nearly follow ing the $-M$ direction ( $0 \quad 0: 05$ ). iii) $Q=\left(1-_{1}\right.$ $\left.2+0.5+{ }_{2}\right)$, while nearly follow ing the A-L direction ( $0 \quad 1 ; 2 \quad 0: 04$ ). The choice of $B Z$ points $m$ easured was dependent on a series of conditions including the need to optim ize the structure factors, single ( -A ) or $m$ ulti-analyzer ( -M , A -L ) m easurem ent $m$ ode and spectrom eter and tim e lim itations.


FIG.1: (color online) Energy loss scan in alm ost transverse geom etry m easured at $Q=\left(\begin{array}{ll}1 & 2\end{array} 0.3\right)$ corresponding to 0.6 A. The data, nom alized to the incident ux, are shown with the least-squares $t$ (dashed line) and the $a b$-initio spectrum w ith and w ithout broadening due to experim ent and electron phonon coupling (solid lines). T he broad peak corresponds to the dam ped $\mathrm{E}_{2 \mathrm{~g}} \mathrm{~m}$ ode and is shown in greater detail in the inset.T he peak at zero is due to di use scattering.

In Fig. 1 we show data taken at the 0.6 -A point in the B Z.T he acousticm ode asw ellas the low er energy opticalm ode ( $E_{1 u}$ ) are visible as resolution-lim ited peaks. M ost im portantly, a broad peak is observed at higher energy loss, corresponding to the $\mathrm{E}_{2 \mathrm{~g}} \mathrm{~m}$ ode. W e perform ed least square ts to sum $s$ of Lorentzian functions w ith FW HM corresponding to the experim ental resolution for the resolution lim ited peaks and a free param eter for the strongly dam ped phonon. These yield the dispersion as well as the linew idth variation over the B Z . D espite statistical lim itations (3-6 counts per minute on this peak along -A ) and tails of the peaks from the stronger, low energy phonons, the peak energy as well as the linew idth can be estim ated w ith reasonable con dence.

Fig. 2 show s a sim ilar energy loss scan at (0.97 229 0.54 ) close to the $0.58 \mathrm{~A}-\mathrm{z}$ point. A strong acoustic m ode is seen at 30 meV . The peak at 50 m eV corresponds to the $A_{2 u}$ branch and the one at 65 meV to another acoustic branch. Finally two resolved features are seen at 85 and 97 meV . These are the two $\mathrm{E}_{2 \mathrm{~g}} \mathrm{~m}$ odes which in this region of reciprocal space are well separated from other modes. Though, given the statistics, it would be hazardous to estim ate a linew idth, the com parison betw een the experim ental and ab-initio spectra suggests that the linew idths of both the $\mathrm{E}_{2 \mathrm{~g}} \mathrm{~m}$ odes are resolution lim ited and so the dam ping is much less than that along -A. A s for the $m$ easurem ent nearly along $M$, the structure factor for the optical m odes strengthens only near the


F IG . 2: (color on line) E nergy loss scan, m easured at $Q=(0.97$ 2290.54 ) corresponding closely to $0.58 \mathrm{~A}-\mathrm{L}$, w ith the leastsquares $t$ and the $a b$-initio spectrum calculated at $0.58 \mathrm{~A}-\mathrm{L}$.
zone boundary. At the point $m$ easured nearest to $M$ ( $(1.051 .450)$, not show $n$ ) the $E_{2 g}$ and $E_{1 u} m$ odes are com parable in intensity but only separated by about 1 meV according to our calculation and we do m easure a single peak only som ew hat broader (FW HM 10 m eV ) than the experim ental resolution, indicating reduced $\mathrm{E}_{2 \mathrm{~g}}$ linew idth. T he proxim ty of the $E_{1 u} m$ ode how ever prevents a m conclusion in this regard. W e mention that the calculated structure factors and energies show excellent quantitative agreem ent $w$ ith our $m$ easured data of which we have shown only two exam ples.

Sim ilar analysis w as done for severalpoints along the three directions in order to experim entally determ ine the phonon dispersion and the linew idths. T he di erence in calculated phonon energies betw een the $m$ easured points and corresponding points exactly along $M$ and $A-$ L $(; 1 ; 2=0)$ is less than half $a \mathrm{meV}$ in all cases. W e can thus com pare the experim ental phonon dispersion $w$ ith the theoretical calculation along the high sym $m$ etry lines, as show $n$ in the bottom panel of $g$ (circles).
$T$ he $m$ easured intrinsic linew idth of the $E_{2 g}$ branch, show $n$ in the top panel of 9 , is strongly anisotropic in the BZ.A long -A it is particularly large (ranging from 20 to 28 meV ), while near L and probably near M it is below the experim ental resolution.

Electronic structure calculations [20] w ere perform ed using DFT in the generalized gradient approxim ation [21]. W e used nom conserving pseudo-potentials [22]. For M g we used non-linear core corrections [23] and we treated the $2 \mathrm{~s}, 2 \mathrm{p}$ levels as core states. T he wavefunctions were expanded in plane waves using a 35 Ry cuto . The calculations w ere perform ed $w$ ith the experim ental crystal structure, nam ely $a=3: 083 \mathrm{~A}$ and $\mathrm{c}=\mathrm{a}=$


FIG. 3: (color online) B ottom : Experim ental (circles) and theoretical phonon dispersion (solid line) in MgB 2 along $A$ and $M$ and $A-$. In the region near the $M$ point, the probable detection of the $\mathrm{E}_{2 \mathrm{~g}} \mathrm{~m}$ ode is indicated w ith a square sym bol (see text). The crosses indicate a parasite signal of unknown origin. Top: Intrinsic linew idth of the $E_{2 \mathrm{~g}} \mathrm{~m}$ ode. $T$ he experim ental linew idth (circles) is large along -A and below the experim ental resolution (dashed line) near $L$ and M.The theoretical result (diam onds) for the electron-phonon coupling contribution to the linew idth is also shown. A long $A-$ and $M$ where the $E 2 g \mathrm{~m}$ ode is non-degenerate both theoretical values are shown, when di erent. E 2 g linew idth decreases progressively from $A$ to $L$ and experim entally the tw o branches are resolved for the point nearest to $L$.

1:142. T he harm onic phonon frequencies w ere com puted in the linear response [24]. W e used a $16 \quad 16$ $M$ onkhorst $P$ ack grid for the electronic BZ integration and rst order $H$ erm ite-G aussian sm earing 25] of 0:025 Ry. The dynam ical m atrix at a given point of the $B Z$ w as obtained from a Fourier intenpolation of the dynam icalm atrices com puted on a $6 \quad 64$ phonon $m$ esh. The resulting phonon frequencies are show in $g .3$ and are in good agreem ent w th a recent calculation [11]. T he agreem ent $w$ ith experim ent is rem arkable.

The contribution to the FW HM linew idth $q$ at mo$m$ entum $q$ for the phonon $m$ ode due to the electronphonon interaction can be written as 15]:
where the sum is extended over the $\mathrm{BZ}, \mathrm{N}_{\mathrm{k}}$ is the number of $k$-points in the sum, and ${ }^{k n}$ are the energy bands $m$ easured with respect to the Ferm i level at point $k$. The $m_{p}$ atrix elem ent is $g_{k n ; k+q m}=$ $h k n j V=u_{q} k+q m i={ }^{P} \overline{2!q}$, where $u_{q}$ is the amplitude of the displacem ent of the phonon of wavevector $q,!q$ is the phonon frequency and $V$ is the $K$ ohn-Sham potential.

In the calculations we used $\mathrm{N}_{\mathrm{k}}=30^{3}$ inequivalent k points and, in Eqs. (1) and (3), we substituted the functions w th G aussians. T he electron phonon coupling q is obtained from the linew idth [15] as:

$$
\begin{equation*}
\mathrm{q}=\frac{\mathrm{q}}{2 \mathrm{~N}(0)!{ }_{\mathrm{q}}^{2}} \tag{2}
\end{equation*}
$$

$N(0)=0: 354$ states $/\left(M \mathrm{gB}_{2} \mathrm{eV}\right.$ spin) being the density of states at the Ferm i level.
$T$ he second contribution to the linew idth is given by the anharm onicity in the crystal potential. At lowest order for them ode of a zone center phonon the FW HM linew idth is 16, 26, 27]:

$$
\begin{equation*}
0={\frac{h}{8 N_{q}}}_{q ;}^{\mathrm{X}_{\mathrm{q}}} \frac{@^{3} \mathrm{E}}{\mathrm{@u}_{0} @_{\mathrm{q}} \mathrm{Qu}_{\mathrm{q}}} \xlongequal{\jmath} \frac{I_{\mathrm{q}}^{\mathrm{D}} \quad+\mathrm{I}_{\mathrm{q}}^{\mathrm{A}}}{!_{0}!_{\mathrm{q}}!_{\mathrm{q}}} \tag{3}
\end{equation*}
$$

E being the total energy, $\mathrm{n}_{\mathrm{q}}$ the Bose occupation for mode at $w$ avevector $q$, $I_{q}^{D}=\left(n_{q}+\right.$ $\left.\mathrm{n}_{\mathrm{q}}+1\right)\left(!_{0} \quad!_{\mathrm{q}} \quad!_{\mathrm{q}}\right)$ describes the decay in the two phonons and , and $I_{q}^{A}=2\left(n_{q}\right.$ $\mathrm{n}_{\mathrm{q}}$ ) (! $\mathrm{l}_{\mathrm{q}} \quad \mathrm{l}_{\mathrm{q}}+!_{\mathrm{q}}$ ) describes the -phonon absonption and the -phonon em ission.

W e com puted the anharm onic linew idth at the highsym m etry points , A, M. For the calculation at A we considera 112 supercellw ith 6 atom $s$, while for the $M$ pointwe use a 21 œellw ith 12 atom s . The third order $m$ atrioes w ere evaluated using linear response theory and the $2 n+1$ theorem for $m$ etals [28]. The anharm onic contribution was evaluated at 0 K and 300K.

At the anharm onic linew idth is largest for the $\mathrm{E}_{2 \mathrm{~g}}$ m ode and equal to $0: 16 \mathrm{meV}$ at $\mathrm{T}=0 \mathrm{~K}$ and $1: 21 \mathrm{meV}$ at $T=300 \mathrm{~K}$. B oth the values are negligible if com pared w ith the experim ental Ram an linew idth of roughly 40 meV [13], suggesting that the $m$ ain source ofbroadening is the electron-phonon interaction.

The results of the calculation of the two contributions to the linew idth at $A$ and $M$ are show $n$ in $T a b l e[$. At the A point the linew idth of the $\mathrm{E}_{2 \mathrm{~g}} \mathrm{~m}$ ode due to electronphonon scattering is very large while the anharm onic contribution is $m$ ore than an order of $m$ agnitude $s m$ aller. For sizable values of the EPC and at low tem perature the anharm onicity is negligible show ing that a m easure$m$ ent of the linew idth at $q$ for the $m$ ode is essentially equivalent to determ ining $q$. This is unexpected since earlier theoretical w ork $[3,4,4]$ estim ates anharm onicity to be im portant for a di erent but related quantity, the frequency shift.

Since the anharm onic contribution is negligible at, A, M, and com putationally dem anding, we only evaluated the EPC linew idth for the other points along the three directions. U sing the calculated phonon frequencies, displacem ents and linew idths we com pute the structure factors for one phonon processes using the $X$-ray form factors, obtaining good agreem ent $w$ th experim ent as show $n$ in $F$ igs. [1.2. In the top panelofF ig. 3 w show

| M |  |  |  |  |  | A |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| 0 | 300 |  |  | 0 | 300 |  |  |  |  |
| 0.00 | 0.12 | 0.00 | 0.00 | 0.00 | 0.17 | 0.00 | 0.00 |  |  |
| 0.00 | 0.15 | 0.01 | 0.01 | 0.00 | 0.17 | 0.00 | 0.00 |  |  |
| 0.02 | 0.12 | 0.06 | 0.02 | 0.00 | 0.63 | 0.08 | 0.05 |  |  |
| 0.12 | 0.48 | 1.13 | 0.20 | 0.00 | 0.63 | 0.08 | 0.05 |  |  |
| 0.06 | 0.25 | 0.00 | 0.00 | 0.02 | 0.22 | 0.84 | 0.28 |  |  |
| 0.07 | 0.33 | 2.34 | 0.30 | 0.02 | 0.20 | 0.08 | 0.02 |  |  |
| 0.26 | 0.42 | 1.06 | 0.06 | 0.10 | 2.13 | 20.35 | 2.83 |  |  |
| 0.45 | 0.69 | 1.21 | 0.07 | 0.10 | 2.13 | 20.35 | 2.83 |  |  |
| 0.47 | 0.72 | 0.08 | 0.00 | 0.13 | 0.23 | 0.05 | 0.00 |  |  |

TA B LE I: C alculated linew idths ( m eV ) due to anharm onicity at OK ( ${ }^{0}$ ), 300K ( ${ }^{300}$ ) and electron-phonon interaction at $M$ and $A$ for allm odes. Phonon frequencies increase from top to bottom . is the electron-phonon coupling. $\mathrm{E}_{2 \mathrm{~g}} \mathrm{~m}$ odes in boldface.

| q | 02 -A | 0.5 -A | 0.6 -A | 0.8 -A | 1.0 -A |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\begin{aligned} & \text { expt: } \\ & \text { q } \end{aligned}$ | 2.51 .1 | 2.60 .6 | $2.3 \quad 0.5$ | 3.60 .7 | 3.60 .8 |
| $\begin{aligned} & \text { theo: } \\ & \mathrm{g} \end{aligned}$ | 3.32 | 2.80 | 2.77 | 3.12 | 2.83 |

TABLE II: Experim ental and theoretical q of each of the tw $O$ degenerate $E_{2 g} \mathrm{~m}$ odes along -A .
the theoretical results for the $\mathrm{E}_{2 \mathrm{~g}}$ branch. T he result is consistent w ith the experim ental value w herever the $\mathrm{E}_{2 \mathrm{~g}}$ branch is clearly visible nam ely along -A and near the L point. Finally, the anham onicity being negligible, we used Eq. (2) to extract $q$ of the $\mathrm{E}_{2 \mathrm{~g}} \mathrm{~m}$ ode along -A using the $m$ easured linew idths and frequencies together w ith the calculated electronic density of states. In Table II the experim ental values are com pared $w$ th the theoretical predictions. The anom alously large EPC along
$-A$ is due to the nesting factor of the $B$ bonding $p_{x ; y}$ Ferm i surfaces, which are concentric cylinders centered on -A [ , 6]. The $E_{2 \mathrm{~g}} \mathrm{~m}$ odes, which m odify the $B-B$ distances, are the only ones $w$ th a sizeable $m$ atrix ele$m$ ent, $g_{k n ; k+q m}$, betw een electrons on these surfaces.

In conclusion, we have $m$ easured phonon dispersion and linew idths in a sub-m $m$ sized $M \mathrm{gB}_{2}$ crystal $w$ ith inelastic $X$-ray scattering con $m$ ing the power and versatility of this technique. Both acoustic and optical $m$ odes are detected and we nd that the $E_{2 g} m$ ode is anom alously broadened along -A but that this broadening is not generalized over the B rillouin Zone. O ur D ensity Functional T heory calculations of the dispersion and linew idth are in excellent agreem ent $w$ ith experi$m$ ent. They show that the dom inant contribution to the broadening for allm odes is the electron-phonon coupling, the anharm onic contribution being $m$ uch $s m$ aller. Thus phonon linew idth in $\mathrm{M} \mathrm{gB}_{2}$ is a direct $m$ easure ofelectronphonon coupling and could, w ith the availability of larger
sam ples, be $m$ easured for allm odes over the whole $B$ rillouin zone so as to extract the anisotropic E liashberg coupling function.

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